

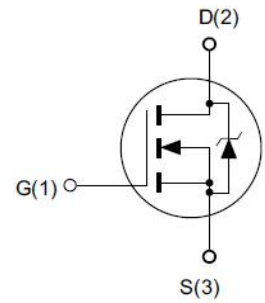


MPC11N40

N-Channel Power MOSFET

Features

- ◆ 400V, 11A, $R_{DS(ON)}(Typ.) = 0.46\Omega @ V_{GS} = 10V$.
- ◆ Low C_{rss}
- ◆ Fast Switching
- ◆ 100% Avalanche Tested



TO-220

Application

- ◆ Power switch circuit of adaptor and charger

Absolute Maximum Ratings $T_c = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Voltage ^a	400	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous, $T_C = 25^\circ C$	11	A
	Drain Current-Continuous, $T_C = 100^\circ C$	6.3	A
I_{DM}	Drain Current-Pulsed ^b	40	A
P_D	Maximum Power Dissipation @ $T_J = 25^\circ C$	100	W
dv/dt	Peak Diode Recovery dv/dt ^c	5.0	V/ns
E_{AS}	Single Pulsed Avalanche Energy ^d	450	mJ
T_J, T_{STG}	Operating and Store Temperature Range	150, -55 to 150	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.25	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	$^\circ C/W$

Electrical Characteristics $T_J = 25^\circ C$ unless otherwise noted

■ Off Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	400	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 400V, V_{GS} = 0V$	-	-	1	μA
I_{GSS}	Forward Gate Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 30V$	-	-	± 100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	-	4	V



MPC11N40

N-Channel Power MOSFET

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10V, I_D = 5.5A$	-	0.46	0.55	Ω
g_{fs}	Forward Transconductance	$V_{DS}=15V, I_D=5.5A$	-	8.5	-	S

■ Dynamic Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
C_{iss}	Input Capacitance	$V_{DS} = 25V,$ $V_{GS} = 0V,$ $f = 1.0MHz$	-	1126	-	pF
C_{oss}	Output Capacitance		-	124	-	pF
C_{rss}	Reverse Transfer Capacitance		-	8	-	pF

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 200V, I_D = 11A,$ $V_{GS}=10V$	-	18	-	ns
t_r	Turn-On Rise Time		-	23	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	41	-	ns
t_f	Turn-Off Fall Time		-	19	-	ns
Q_g	Total Gate Charge	$V_{DS} = 320V, I_D = 11A,$ $V_{GS} = 10V$	-	23	-	nC
Q_{gs}	Gate-Source Charge		-	5.2	-	nC
Q_{gd}	Gate-Drain Charge		-	8.5	-	nC

■ Drain-Source Diode Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I_S	Drain-Source Diode Forward Continuous Current	$V_{GS} = 0V$	-	-	10	A
I_{SM}	Maximum Pulsed Current	$V_{GS} = 0V$	-	-	40	A
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0V, I_S = 11A$	-	-	1.5	V
T_{rr}	Body Diode Reverse Recovery Time	$I_S=11A, V_{GS} = 0V$ $dI_F/dt=100A/us$	-	376	-	ns
Q_{rr}	Body Diode Reverse Recovery Charge	$I_S=11A, V_{GS} = 0V$ $dI_F/dt=100A/us$	-	2560	-	nC

Notes:

- $T_J=+25\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$
- Repetitive rating; pulse width limited by maximum junction temperature.
- $I_{SD} = 11A, dI_F/dt \leq 100A/us, V_{DD} \leq BV_{DS}$, Start $T_J=25\text{ }^{\circ}\text{C}$.
- $L = 10mH, V_{DD}=50V, I_{AS} = 9.5A, R_G=25\Omega$ Starting $T_J=25\text{ }^{\circ}\text{C}$.

■ Characteristic Curve

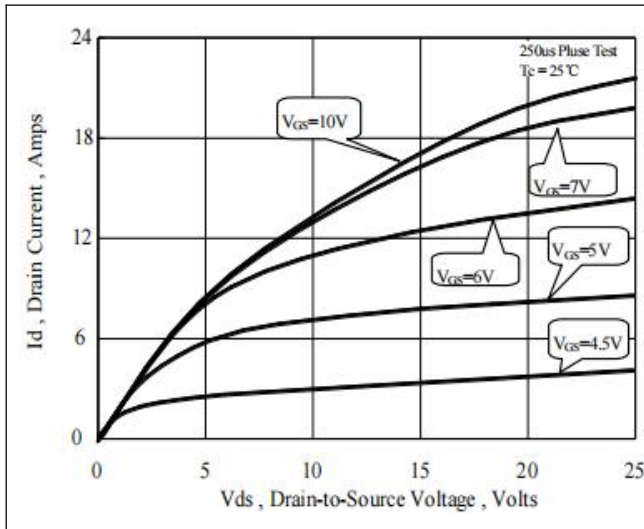


Figure 1. Typical Output Characteristics

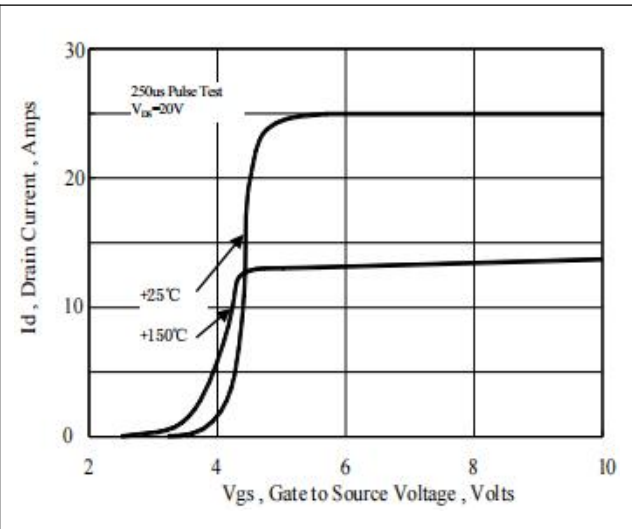


Figure 2. Typical Transfer Characteristics

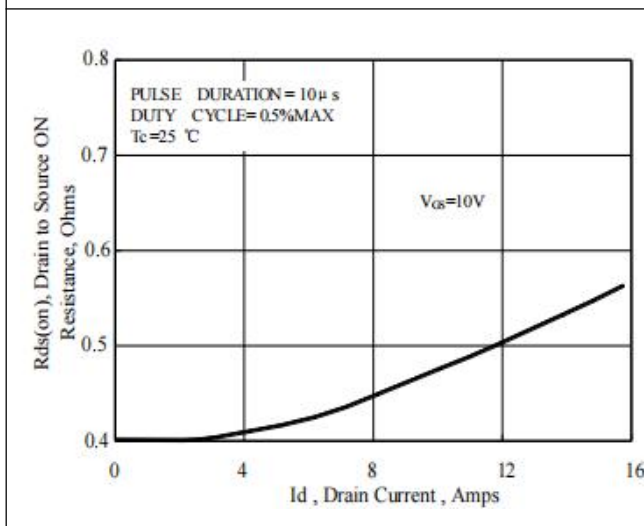


Figure 3. On- Resistance vs. Drain Current

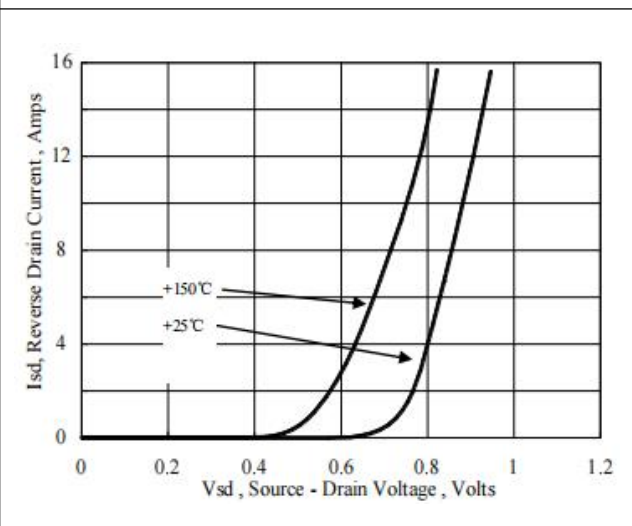


Figure 4. Body-Diode Characteristics

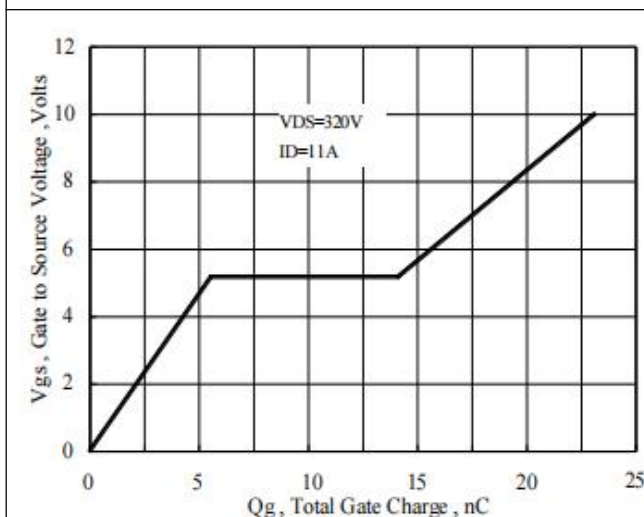


Figure 5. Gate-Charge Characteristics

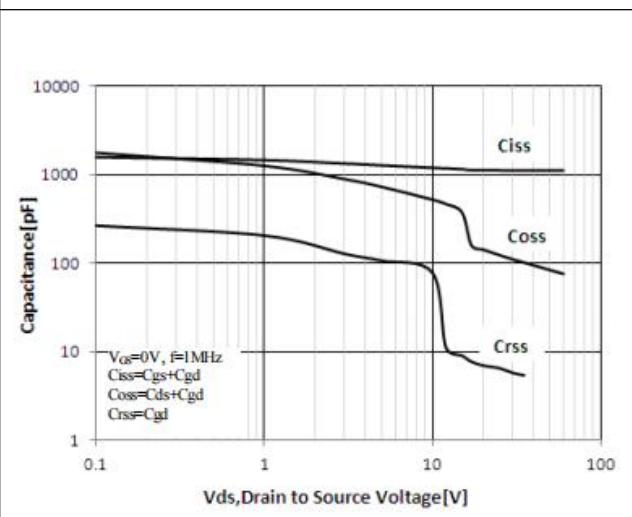


Figure 6. Capacitance Characteristics

■ Characteristic Curve

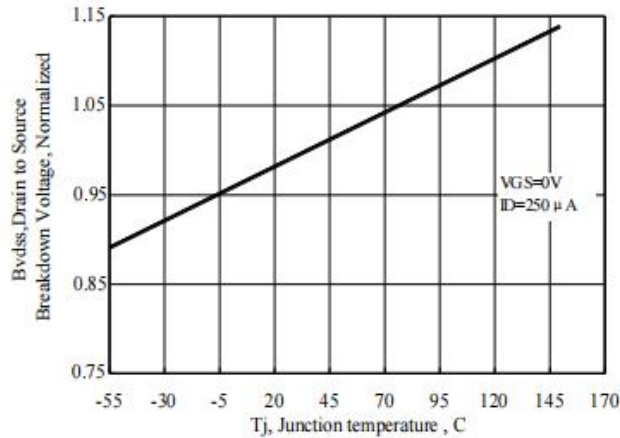


Figure 7. Normalized Breakdown voltage vs. Junction Temperature

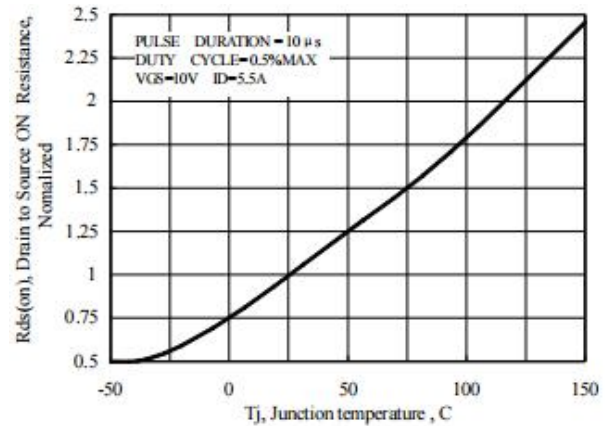


Figure 8. Normalized on Resistance vs. Junction Temperature

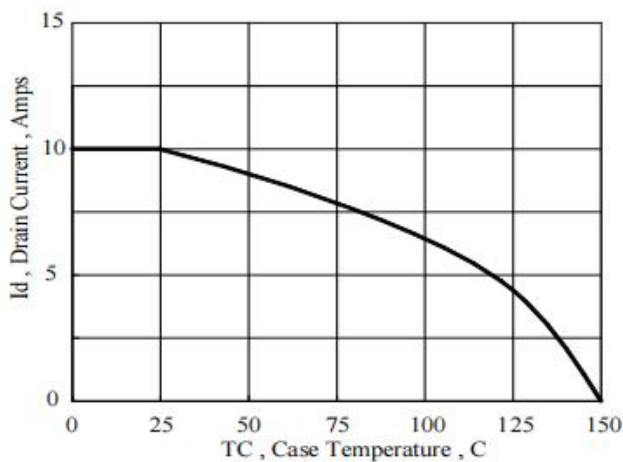


Figure 9: Maximum Continuous Drain Current vs. Case Temperature

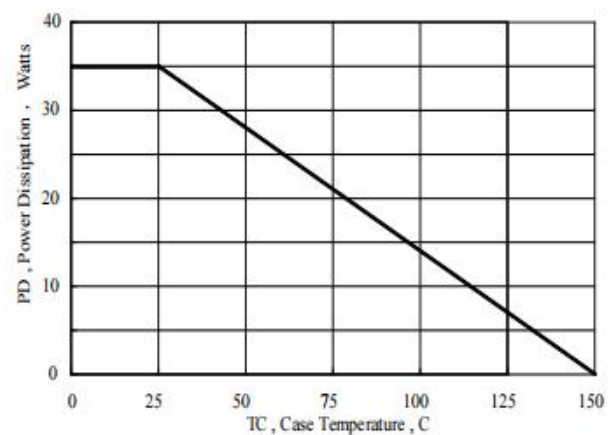


Figure 10: Maximum Power Dissipation vs Case Temperature

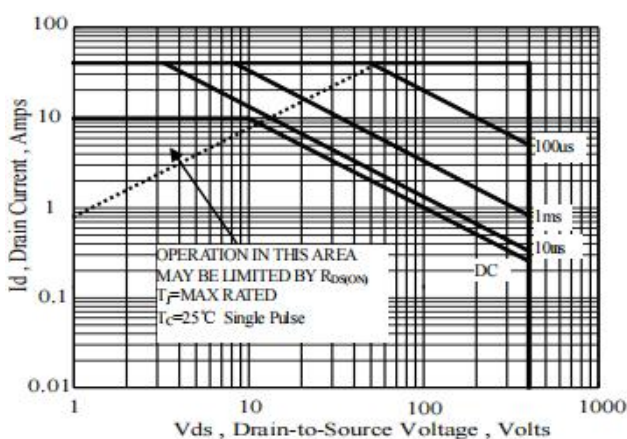


Figure 11. Maximum Safe Operating Area

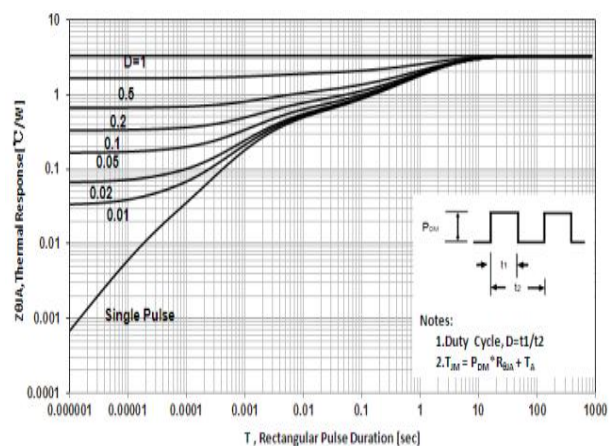


Figure 12: Normalized Maximum Transient Thermal Impedance

■ Package Information

